

# 2SB1143/2SD1683

# **50V/4A Switching Applications**

# **Applications**

· Voltage regulators, relay drivers, lamp drivers, electrical equipment.

#### **Features**

- · Adoption of FBET, MBIT processes.
- · Low saturation voltage.
- · Large current capacity and wide ASO.

(): 2SB1143

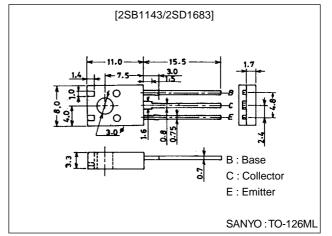
# **Specifications**

### Absolute Maximum Ratings at Ta = 25°C

# **Package Dimensions**

unit:mm

2042A



Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V <sub>CBO</sub>		(–)60	V
Collector-to-Emitter Voltage	VCEO		(-)50	V
Emitter-to-Base Voltage	V <sub>EBO</sub>		(-)6	V
Collector Current	IC		(-)4	Α
Collector Current (Pulse)	I <sub>CP</sub>		(-)6	Α
Collector Dissipation	PC		1.5	W
		Tc=25°C	10	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

#### Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions	Ratings			Unit
	Symbol		min	typ	max	Offic
Collector Cutoff Current	I <sub>CBO</sub>	V <sub>CB</sub> =(-)40V, I <sub>E</sub> =0			(–)1	μA
Emitter Cutoff Current	I <sub>EBO</sub>	V <sub>EB</sub> =(-)4V, I <sub>C</sub> =0			(-)1	μA
DC Current Gain	h <sub>FE</sub> 1	V <sub>CE</sub> =(-)2V, I <sub>C</sub> =(-)100mA	100*		560*	
	h <sub>FE</sub> 2	V <sub>CE</sub> =(-)2V, I <sub>C</sub> =(-)3A	40			
Gain-Bandwidth Product	f <sub>T</sub>	V <sub>CE</sub> =(-)10V, I <sub>C</sub> =(-)50mA		150		MHz
Output Capacitance	C <sub>ob</sub>	V <sub>CB</sub> =(-)10V, f=1MHz		(39)25		pF

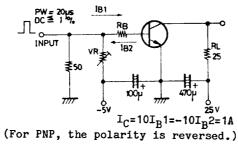
 $<sup>\</sup>ensuremath{^*}$  ; The 2SB1143/2SD1683 are classified by 100mA  $\ensuremath{h_{FE}}$  as follows :

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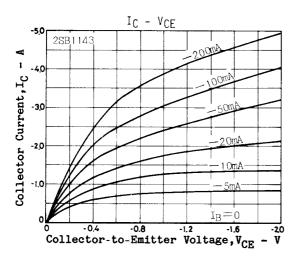
## 2SB1143/2SD1683

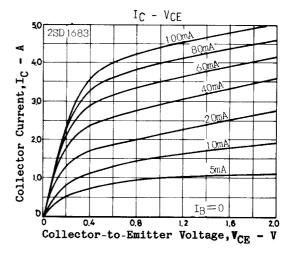
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Unit
Collector-to-Emitter Saturation Voltage	VCE(sat)	I <sub>C</sub> =(-)2A, I <sub>B</sub> =(-)100mA		(-350)	(-700)	mV
				190	500	mV
Base-to-Emitter Saturation Voltage	V <sub>BE(sat)</sub>	I <sub>C</sub> =(-)2A, I <sub>B</sub> =(-)100mA		(-)0.94	(–)1.2	V
Collector-to-Base Breakdown Voltage	V(BR)CBO	I <sub>C</sub> =(-)10μΑ, I <sub>E</sub> =0	(-)60			V
Collector-to-Emitter Breakdown Voltage	V <sub>(BR)</sub> CEO	I <sub>C</sub> =(-)1mA, R <sub>BE</sub> =∞	(–)50			V
Emitter-to-Base Breakdown Voltage	V <sub>(BR)EBO</sub>	$I_{E}=(-)10\mu A, I_{C}=0$	(–)6			V
Turn-ON Time	ton	See specified Test Circuit		(70)70		ns
Storage Time	t <sub>stg</sub>	See specified Test Circuit		(450)		ns
				650		ns
Fall Time	t <sub>f</sub>	See specified Test Circuit		(30)35		ns

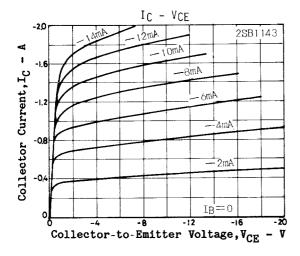
## **Switching Time Test Circuit**

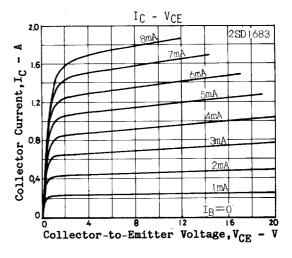


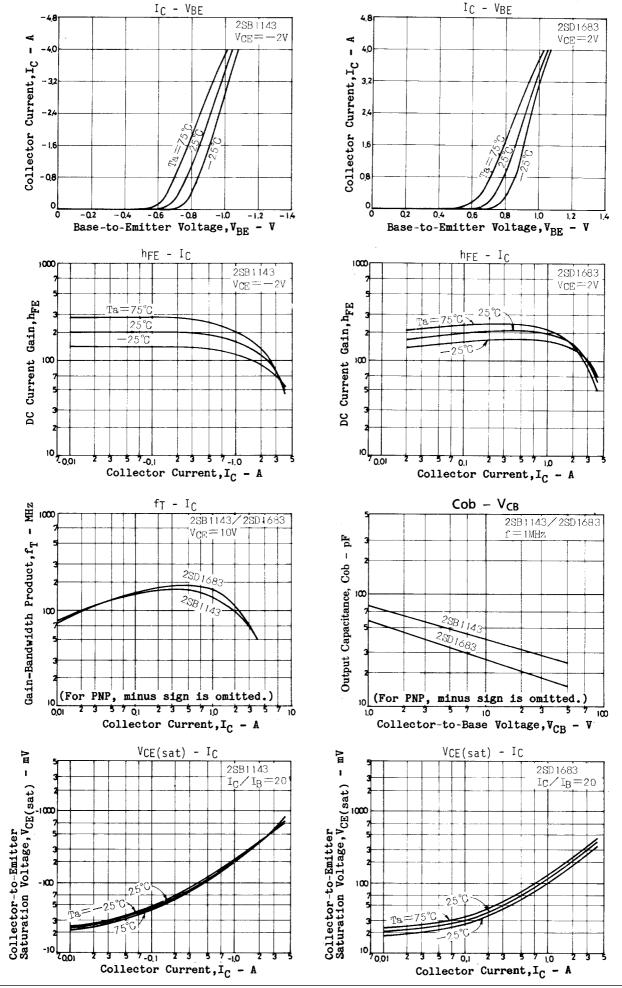
Unit (resistance:  $\Omega$ , capacitance: F)



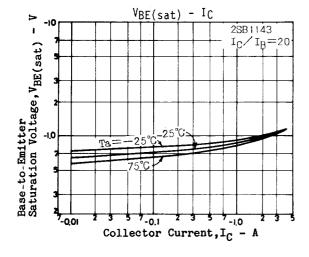


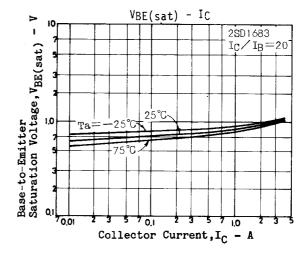


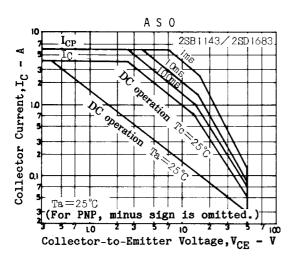


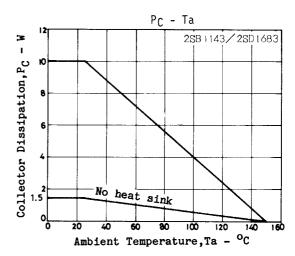


#### 2SB1143/2SD1683









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